

Please type a plus sign (+) inside this box → [+]

PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	Based on 09/640,077
				Filing Date	August 17, 2000
				First Named Inventor	Ritsuko KAWASAKI, et al.
				Group Art Unit	2813
				Examiner Name	Laura Schillinger
				Attorney Docket Number	0756-7181
Sheet	1	of	2		

U.S. PATENT DOCUMENTS						
Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ³ (if known)			
A-S		5,923,962		Ohtani et al.	07/13/99	
		5,643,826		Ohtani et al.	07/01/97	

FOREIGN PATENT DOCUMENTS								
Examiner Initials ¹	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁴
		Office ²	Number ²	Kind Code ³ (if known)				
A-S		JP	07-130652			05/19/95		Abst.

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁴
A-S		K. Shimizu et al., "High-Mobility Poly-Si Thin-Film Transistors Fabricated by a Novel Excimer Laser Crystallization Method," IEEE Transactions on Electron Devices, Vol. 40, No. 1, pp. 112-117, 1993.	
		Ishihara et al., "Location-Controlled Adjacent Grains Following Excimer-Laser Melting of Si Thin-Films," 1998, pp. 153-156, AM-LCD.	
		Specifications and Drawings for Application Serial No. 09/696,165, "Semiconductor Device and Method of Manufacturing the Same," Filed on 10/26/00, pp. 1-63, 33 pages of drawings, Inventors: Ritsuko KAWASAKI, et al.	
		Specifications and Drawings for Application Serial No. 09/598,827, "Method of Fabricating a Semiconductor Device," Filed on 06/21/00, pp. 1-64, 25 pages of drawings, Inventor: Kenji KASAHARA.	
		Specifications and Drawings for Application Serial No. 09/732,724, "Semiconductor Device and A Method of Manufacturing the Same," Filed on 12/11/00, pp. 1-50, 26 pages of drawings, Inventors: Ritsuko KAWASAKI et al.	
		Ishihara et al., "Location Control of Large Grain Following Excimer-Laser Melting of Si Thin-Films," March 1998, pp. 1071-1075, Japanese Journal of Applied Physics, Vol. 37, Pt. 1, No. 3B.	

Examiner Signature	<i>A-S</i>	Date Considered	3/1/05
--------------------	------------	-----------------	--------

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, Washington, DC 20231.

Please type a plus sign (+) inside this box → (+)

PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Complete if Known	
		Application Number	Based on 09/640,077
		Filing Date	August 17, 2000
		First Named Inventor	Ritsuko KAWASAKI, et al.
		Group Art Unit	2813
		Examiner Name	Laura Schillinger
Sheet	2	of	2
		Attorney Docket Number	0756-7181

U.S. PATENT DOCUMENTS						
Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
AS		5,893,730		Yamazaki et al.	04/13/99	
		6,078,070		Robinson	06/20/00	
		6,107,107		Bruce et al.	08/22/00	
		6,245,602		Ho et al.	06/12/01	
		5,811,322		Robinson	09/22/98	
		5,841,197		Adamic Jr.	11/24/98	
		6,346,438		Yagishita et al.	02/12/02	
		6,285,042		Ohtani et al.	09/04/01	
		6,335,451		Ohtani et al.	01/01/02	
		6,492,659		Yamazaki et al.	12/10/02	

FOREIGN PATENT DOCUMENTS							
Examiner Initials ¹	Cite No. ¹	Foreign Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁴
		Office ³	Number ⁴ (if known)				
AS		JP	2001-203360		07/27/01		Full

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²

Examiner Signature	AS	Date Considered	4/5/05
--------------------	----	-----------------	--------

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, Washington, DC 20231.